

# SGM58031 Ultra-Small, Low-Power, 16-Bit ADC with Internal Reference

## **GENERAL DESCRIPTION**

The SGM58031 is a low-power, 16-bit, precision, delta-sigma ( $\Delta\Sigma$ ) analog-to-digital converter (ADC). It operates from a 3V to 5.5V supply.

The SGM58031 contains an on-chip reference and oscillator. It has an  $I^2$ C-compatible interface, and it can select four  $I^2$ C slave addresses. The date rate of the filter is up to 960SPS. The SGM58031 has an on-chip PGA, which can provide input ranges to as low as ±256mV from the power supply.

The input multiplexer supports 4 single-ended inputs or 2 differential inputs configuration.

The SGM58031 is available in Green MSOP-10 and TDFN-3×3-10L packages. It operates over an ambient temperature range of -40°C to +125°C.

## **FEATURES**

- Single-Supply Voltage Range: 3V to 5.5V
  - I<sup>2</sup>C Bus Voltage Range: 3V to 5.5V
- Low Quiescent Current:
  - Continuous Mode: 255µA (TYP)
  - Power-Down Mode: 0.8µA (TYP)
- Selectable Date Rates: 6.25SPS to 960SPS
- Input Multiplexer
  - 4 Single-Ended Inputs or 2 Differential Inputs
- Internal Programmable Gain Amplifier (PGA)
- Internal Voltage Reference and Oscillator
- Selectable Digital Comparator
- I<sup>2</sup>C-Compatible Serial Interface
- Available in Green MSOP-10 and TDFN-3×3-10L Packages

## **APPLICATIONS**

Portable Devices Process Control Battery Monitoring System Temperature Measurement



## SGM58031

## PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM58031	MSOP-10	-40°C to +125°C	SGM58031XMS10G/TR	SGM58031 XMS10 XXXXX	Tape and Reel, 4000
361036031	TDFN-3×3-10L	-40°C to +125°C	SGM58031XTD10G/TR	SGM 58031D XXXXX	Tape and Reel, 4000

### MARKING INFORMATION

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.



Uendor Code

— Trace Code

— Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

### **ABSOLUTE MAXIMUM RATINGS**

Voltage Range (with Respect to GND)

V <sub>DD</sub>	0.3V to 5.5V
Analog Input Voltage	0.3V to 5.5V
SDA, SCL, ADDR, ALERT/RDY Voltage	0.3V to 5.5V
Input Current (Momentary)	100mA
Input Current (Continuous)	10mA
Junction Temperature	
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	4000V
CDM	1000V

#### **RECOMMENDED OPERATING CONDITIONS**

Operating Temperature Range .....-40°C to +125°C

### **OVERSTRESS CAUTION**

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

### **ESD SENSITIVITY CAUTION**

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

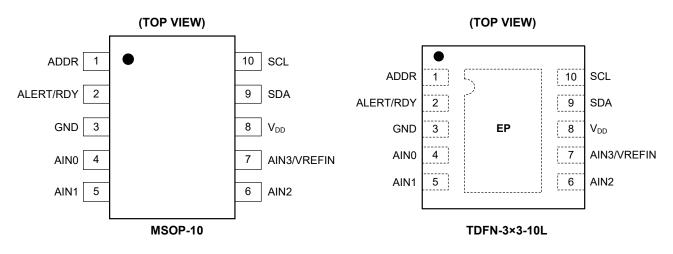
#### DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.



## SGM58031

## **PIN CONFIGURATIONS**



## **PIN DESCRIPTION**

I	PIN	NAME	<b>TYPE</b> <sup>(1)</sup>	FUNCTION
MSOP-10	TDFN-3×3-10L		TTPE	FUNCTION
1	1	ADDR	DI	I <sup>2</sup> C Address Selection Pin.
2	2	ALERT/RDY	DO	Digital Comparator Output/Conversion Ready Pin.
3	3	GND	G	Ground.
4	4	AIN0	AI	Positive Input of Differential Channel 1 or Input of Single-Ended Channel 1.
5	5	AIN1	AI	Negative Input of Differential Channel 1 or Input of Single-Ended Channel 2.
6	6	AIN2	AI	Positive Input of Differential Channel 2 or Input of Single-Ended Channel 3.
7	7	AIN3/VREFIN	AI	Negative Input of Differential Channel 2, or Input of Single-Ended Channel 4, or External Reference Input.
8	8	V <sub>DD</sub>	Р	Power Supply Pin. It can be operated from 3V to 5.5V
9	9	SDA	DIO	Serial Data Pin.
10	10	SCL	DI	Serial Clock Input Pin.
_	Exposed Pad	EP	-	Exposed pad should be soldered to PCB board and connected to GND.

#### NOTE:

1. AI = Analog Input, DI = Digital Input, DO = Digital Output, DIO = Digital Input and Output, P = Power, G = Ground.



# **ELECTRICAL CHARACTERISTICS**

 $(V_{DD} = 3.3V, Full-Scale (FS) = \pm 2.048V, maximum and minimum specifications apply from T_A = -40°C to +125°C, typical values are at T_A = +25°C, unless otherwise noted.)$ 

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Analog Input	•		•			•
Full-Scale Input Voltage (1)		$V_{IN} = (AIN_P) - (AIN_N)$		±4.096/PGA		V
Analog Input Voltage		AIN <sub>P</sub> or AIN <sub>N</sub> to GND	GND		$V_{\text{DD}}$	V
Differential Input Impedance				See Table 1		
System Performance						•
Resolution		No missing codes	16			Bits
Data Rate	DR			See Table 2		SPS
Data Rate Variation		All data rates	-6		6	%
Output Noise			See	Table 3 and Tab	ole 4	
Integral Nonlinearity	INL	DR = 8SPS, FS = ±2.048V, best fit (99% of full-scale)		1	4	LSB
Offset Error		FS = ±2.048V, differential inputs		1	5	LSB
Oliset Elloi		FS = ±2.048V, single-ended inputs		2	8.5	LSD
Offset Drift		FS = ±2.048V		0.005	0.06	LSB/°C
Offset Power-Supply Rejection		FS = ±2.048V		1.2		LSB/V
Gain Error <sup>(2)</sup>		FS = ±2.048V at +25°C		0.03	0.3	%
		FS = ±0.256V		30		
Gain Drift <sup>(3)</sup>		FS = ±2.048V		30	70	ppm/°C
		FS = ±6.144V <sup>(1)</sup>		30		
Gain Power-Supply Rejection				50	200	ppm/V
PGA Gain Match (2)		Match between any two PGA gains		0.1	0.28	%
Gain Match		Match between any two inputs		0.01	0.08	%
Offset Match		Match between any two gains		1	8.5	LSB
50/60Hz Rejection		FS = ±2.048V		95		dB
Channel-to-Channel Crosstalk		At DC and FS = ±2.048V, differential or single-ended inputs adjacent channels		90		dB
		At DC and FS = ±0.256V		110		
Common-Mode Rejection Ratio	CMRR	At DC and FS = ±2.048V		110		dB
		At DC and FS = $\pm 6.144V^{(1)}$		110		
Internal Clock						
Frequency			386	410	434	kHz

NOTES:

1. The full-scale range of the ADC scaling. In any event, it should not exceed  $V_{DD}$  + 0.3V be applied to this device.

2. It includes all errors from on-chip PGA and reference.

3. Gain temperature drift is defined as the maximum change of gain error measured over the specified temperature range. The gain error drift is calculated using the box method, as described by Equation: Gain Error Drift =  $(GE_{MAX} - GE_{MIN})/(T_{MAX} - T_{MIN})$  where:

-  $\mathsf{GE}_{\mathsf{MAX}}$  and  $\mathsf{GE}_{\mathsf{MIN}}$  are the maximum and minimum gain errors, respectively.

• T<sub>MAX</sub> and T<sub>MIN</sub> are the maximum and minimum temperatures, respectively, over the temperature range -40°C to +125°C.

# **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{DD} = 3.3V, Full-Scale (FS) = \pm 2.048V, maximum and minimum specifications apply from T_A = -40°C to +125°C, typical values are at T_A = +25°C, unless otherwise noted.)$ 

PARAMETER	SYMBOL		CONDITIONS	MIN	TYP	MAX	UNITS
Reference							
Internal Reference					2.048		V
External Reference				0.5		2.5	V
External Reference Input Current		VREFIN = 2	2.5V, continuous mode		0.45		μA
Digital Input/Output							
High Input Voltage (4)	VIH			0.7×V <sub>BUS</sub>			V
Low Input Voltage (4)	VIL					0.3×V <sub>BUS</sub>	V
Low Output Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 3mA			0.07	0.4	V
High Input Leakage Current <sup>(5)</sup>	I <sub>IH</sub>	V <sub>IH</sub> = 5.5V			0.1	1	μA
Low Input Leakage Current (5)	I <sub>IL</sub>	V <sub>IL</sub> = GND			0.1	1	μA
Power-Supply Requirements							
Power-Supply Voltage	V <sub>DD</sub>			3		5.5	V
			Power-down current at +25°C <sup>(6)</sup>		0.8	1	
Cumple Cumple			Power-down current up to +125°C <sup>(6)</sup>		1.8	3.8	
Supply Current	I <sub>DD</sub>	$V_{DD} = 5.5V$	Operating current at +25°C		255	320	μA
			Operating current up to +125°C		270	340	
Deuver Die ein effen		$V_{DD} = 5V$			1.05		
Power Dissipation	PD	V <sub>DD</sub> = 3.3V			0.6		mW

NOTES:

4. There are 2 scenarios:  $V_{DD}$  = 5V,  $V_{BUS}$  can be 3V to 5V;  $V_{DD}$  = 3.3V,  $V_{BUS}$  should be 3.3V. Note that  $V_{BUS}$  = 3V may cause leakage in some extreme conditions, and it's better to make it higher than 3.1V. For  $V_{BUS}$  =  $V_{DD}$ ,  $V_{IL}/V_{IH}$  = 30%/70% of  $V_{BUS}$ . For  $V_{BUS}$  = 3.3V and  $V_{DD}$  = 5V,  $V_{IL}/V_{IH}$  = 20%/80% of  $V_{BUS}$ .

5. Meet the "loss of  $V_{DD}$ " requirement of I<sup>2</sup>C fast mode. When  $V_{DD}$  is lost, the leakage drawn from the pin is controlled.

6. Power-down current increases to 2.3µA at +25°C and 3.5µA at +125°C when Config1 BUS\_FLEX bit is set to '1'.



# TIMING CHARACTERISTICS

PARAMETER	SYMBOL STANDARD MODE		FAST	MODE	HIGH-SPE	ED MODE	UNITS	
PARAMETER	STNIDUL	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
SCL Operating Frequency	f <sub>SCL</sub>	0.01	0.1	0.01	0.4	0.01	3.4	MHz
Bus Free Time between START and STOP Condition	t <sub>BUF</sub>	4700		600		160		ns
Hold Time after Repeated START Condition. After This Period, the First Clock is Generated.	t <sub>HDSTA</sub>	4000		600		160		ns
Repeated START Condition Setup Time	t <sub>susta</sub>	4700		600		160		ns
Stop Condition Setup Time	t <sub>susto</sub>	4000		600		160		ns
Data Hold Time	t <sub>HDDAT</sub>	0		0		0		ns
Data Setup Time	t <sub>SUDAT</sub>	250		100		10		ns
SCL Clock Low Period	t <sub>LOW</sub>	4700		1300		160		ns
SCL Clock High Period	t <sub>HIGH</sub>	4000		600		60		ns
Clock/Data Fall Time <sup>(1)</sup>	t <sub>F</sub>		300		300		160	ns
Clock/Data Rise Time	t <sub>R</sub>		1000		300		160	ns

NOTE:

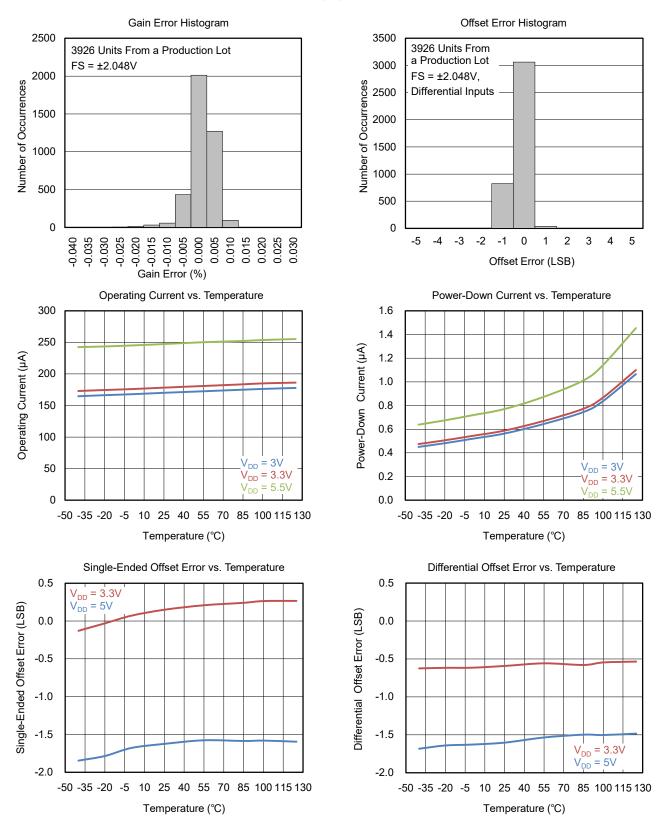
1.  $t_F$  (MIN) for SDA output is 20ns for normal/fast mode and 10ns for high-speed mode. Glitch filter capability is 50ns for normal/fast mode and 10ns for high-speed mode.



## SGM58031

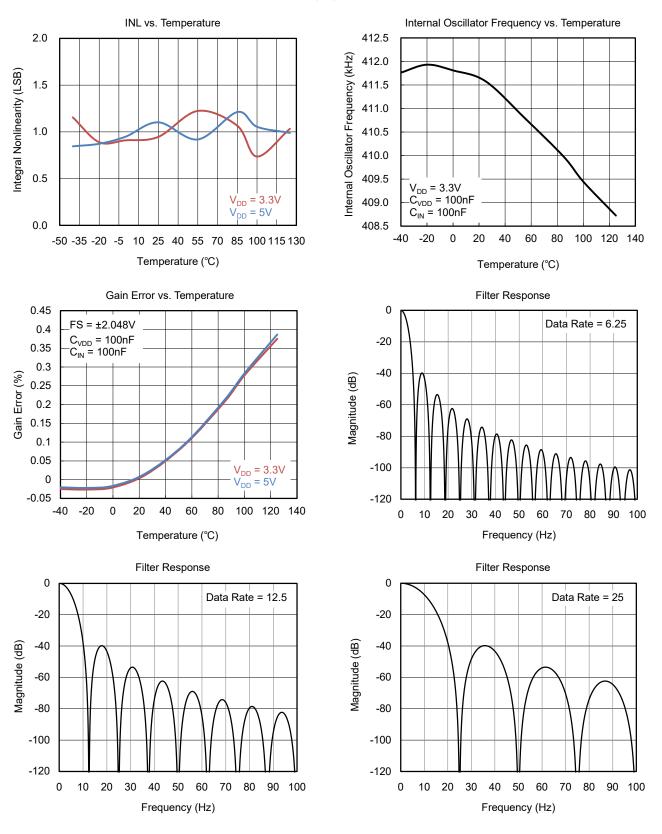
# **TYPICAL PERFORMANCE CHARACTERISTICS**

T<sub>A</sub> = +25°C, V<sub>DD</sub> = 3.3V, Data Rate = 200SPS and Full-Scale (FS) = ±2.048V, unless otherwise noted.



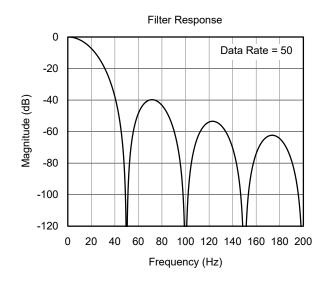
## **TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

T<sub>A</sub> = +25°C, V<sub>DD</sub> = 3.3V, Data Rate = 200SPS and Full-Scale (FS) = ±2.048V, unless otherwise noted.



# **TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

T<sub>A</sub> = +25°C, V<sub>DD</sub> = 3.3V, Data Rate = 200SPS and Full-Scale (FS) = ±2.048V, unless otherwise noted.





## **DETAILED DESCRIPTION**

#### **Analog Inputs**

Table 1. Differential Input Impedance

FS (V)	Differential Input Impedance
±6.144V <sup>(1)</sup>	37.5ΜΩ
±4.096V <sup>(1)</sup>	25ΜΩ
±2.048V	12.5ΜΩ
±1.024V	6.25ΜΩ
±0.512V	6.25ΜΩ
±0.256V	6.25ΜΩ

NOTE: 1. FS = Full-scale range of the ADC scaling. In any event, it should not exceed V<sub>DD</sub> + 0.3V be applied to this device.

### Data Rate

#### Table 2. ADC Output Data Rate (SPS)

DR[2:0] Bits in	DR_SEL Bit in C	Config1 Register
Config Register	DR_SEL = 0	DR_SEL = 1
000	6.25Hz	7.5Hz
001	12.5Hz	15Hz
010	25Hz	30Hz
011	50Hz	60Hz
100	100Hz	120Hz
101	200Hz	240Hz
110	400Hz	480Hz
111	800Hz	960HZ

### **ADC Noise**

#### Table 3. ADC Noise with Internal Reference (RMS in $\mu V)$

DR FS	800	400	200	100	50	25	12.5	6.25
6.144	187.5	187.5	187.5	187.5	187.5	187.5	187.5	187.5
4.096	125	125	125	125	125	125	125	125
2.048	62.5	62.5	62.5	62.5	62.5	62.5	62.5	62.5
1.024	31.25	31.25	31.25	31.25	31.25	31.25	31.25	31.25
0.512	15.62	15.62	15.62	15.62	15.62	15.62	15.62	15.62
0.256	7.81	7.81	7.81	7.81	7.81	7.81	7.81	7.81

#### Table 4. ADC ENOB (ENOB = (20log (FS/Noise\_RMS) - 1.76)/6.02)

DR FS	800	400	200	100	50	25	12.5	6.25
6.144	16	16	16	16	16	16	16	16
4.096	16	16	16	16	16	16	16	16
2.048	16	16	16	16	16	16	16	16
1.024	16	16	16	16	16	16	16	16
0.512	16	16	16	16	16	16	16	16
0.256	16	16	16	16	16	16	16	16



## **REGISTER MAPS**

### **Register Address**

Table 5. Register Address

Address	Register			
0x0	Conversion Register			
0x1	Config Register			
0x2	Lo_Thresh Register			
0x3	Hi_Thresh Register			
0x4	Config1 Register			
0x5	Chip_ID Register			
0x6	GN_Trim1 for EXT_REF Register			

### **Pointer Register**

### Table 6. Pointer Register Byte (Write-Only)

MSB							LSB
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0	0	0	0	0	Register Address		

### **Conversion Register**

Table 7. 16-Bit Conversion Register (Read-Only)

MSB	3									LSB					
Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0

NOTE: Default Value = 0000h.



# **REGISTER MAPS (continued)**

### **Config Register**

Table 8. Config Register Details (Read/Write)

BITS	NAME	DESCRIPTION	COMMENT	DEFAULT VALUE
D[15]	os	Operational Status (Single-Shot Conversion Start) A write status: 0 = No effect 1 = Start a single conversion in power-down mode A read status: 0 = A conversion is being performed currently 1 = A conversion is not being performed currently		
D[14:12]	MUX[2:0]	Input Multiplexer (MUX) Configuration $000 = AIN_P = AIN0$ and $AIN_N = AIN1$ (default) $001 = AIN_P = AIN0$ and $AIN_N = AIN3$ $010 = AIN_P = AIN1$ and $AIN_N = AIN3$ $011 = AIN_P = AIN2$ and $AIN_N = AIN3$ $100 = AIN_P = AIN0$ and $AIN_N = GND$ $101 = AIN_P = AIN1$ and $AIN_N = GND$ $110 = AIN_P = AIN2$ and $AIN_N = GND$ $111 = AIN_P = AIN3$ and $AIN_N = GND$		000
D[11:9]	PGA[2:0]	Programmable Gain Amplifier (PGA) Configuration $000 = FS = \pm 6.144V^{(1)}$ $001 = FS = \pm 4.096V^{(1)}$ $010 = FS = \pm 2.048V$ (default) $011 = FS = \pm 1.024V$ $100 = FS = \pm 0.512V$ $101 = FS = \pm 0.256V$ $111 = FS = \pm 0.256V$		010
D[8]	MODE	Operating Mode 0 = Continuous conversion mode 1 = Power-down single-shot mode (default)		1
D[7:5]	DR[2:0]	Data Rate	These bits control the data rate setting. See Table 2	100
D[4]	COMP_MODE	Comparator Mode 0 = A traditional comparator with hysteresis (default) 1 = A window comparator		0
D[3]	COMP_POL	Comparator Polarity (Control the Polarity of the ALERT/RDY Pin) 0 = Active low (default) 1 = Active high		0
D[2]	COMP_LAT	Latching Comparator 0 = Non-latching comparator (default) 1 = Latching comparator		0
D[1:0]	COMP_QUE[1:0]	Comparator Queue and Disable Function 00 = Assert after one conversion 01 = Assert after two conversions 10 = Assert after four conversions 11 = Disable comparator (default)		11

NOTES:

1. Default Value = 8583h.

2. FS = Full-scale range of the ADC scaling. In any event, it should not exceed  $V_{DD}$  + 0.3V be applied to this device.



# **DETAILED DESCRIPTION (continued)**

### Lo\_Thresh and Hi\_Thresh Registers

Table 9. Lo\_Thresh and Hi\_Thresh Registers (Read/Write)

	Lo_Thresh Register									
Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8			
Lo_Thresh15	Lo_Thresh14	Lo_Thresh13	Lo_Thresh12	Lo_Thresh11	Lo_Thresh10	Lo_Thresh9	Lo_Thresh8			
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0			
Lo_Thresh7	Lo_Thresh6	Lo_Thresh5	Lo_Thresh4	Lo_Thresh3	Lo_Thresh2	Lo_Thresh1	Lo_Thresh0			
			Hi_Thresl	n Register						
Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8			
Hi_Thresh15	Hi_Thresh14	Hi_Thresh13	Hi_Thresh12	Hi_Thresh11	Hi_Thresh10	Hi_Thresh9	Hi_Thresh8			
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0			
Hi_Thresh7	Hi_Thresh6	Hi_Thresh5	Hi_Thresh4	Hi_Thresh3	Hi_Thresh2	Hi_Thresh1	Hi_Thresh0			

NOTE: Lo\_Thresh Default Value = 8000h, Hi\_Thresh Default Value = 7FFFh.

#### Config1 Register Table 10. 16-Bit Config1 Register Details

BITS	NAME	DESCRIPTION	COMMENT	DEFAULT VALUE
D[15:9]	N/A			
D[8]	PD	Writing '1' to PD powers down this part, and this PD bit is automatically cleared internally. Another continuous/single conversion can be carried out again without the need to clear this bit.		0
D[7]	DR_SEL	0 = DR[2:0] = 000 ~ 111 for conversion rate of 6.25Hz, 12.5Hz, 25Hz, 50Hz, 100Hz, 200Hz, 400Hz and 800Hz (default) 1 = DR[2:0] = 000 ~ 111 for conversion rate of 7.5Hz, 15Hz, 30Hz, 60Hz, 120Hz, 240Hz, 480Hz and 960Hz		0
D[6]	BURNOUT	0 = No current sourced (default) 1 = Source a pair of 2µA current to selected pair of AINs		0
D[5]	INT_DIO	0 = None (default) 1 = Select internal diode as ADC input		0
D[4]	BUS_FLEX	0 = Disable leakage blocking circuit for the scenario that $I^2C$ bus voltage is lower than $V_{DD}$ of the part. The $I^2C$ interface is still functional but $V_{DD}$ sees leakage when $V_{BUS} < V_{DD}$ - 0.3V (default) 1 = Bus voltage can be lower than $V_{DD}$ without causing leakage. The $V_{DD}$ range is 3V to 5.5V and the $I^2C$ bus voltage should be limited to 3V to 5.5V		0
D[3]	EXT_REF	0 = None (default) 1 = Use AIN3 as external reference for ADC		0
D[2:0]	N/A			



## **DETAILED DESCRIPTION (continued)**

### Chip\_ID Register

 Table 11. 16-Bit Chip\_ID Register for Identifying Chip ID and Its Subversions (Read-Only)

Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8
N/A	N/A	N/A	ID[4:0]				
0	0	0	0	0	0	0	0
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
	VER[2:0]			N/A	N/A	N/A	N/A
1	0	0	0	0	0	0	0

## GN\_Trim1 Register (When Using EXT\_REF)

ADC gain coefficient for user selecting Config1 register EXT\_REF bit as reference. We provide a default value and user is responsible for writing proper value to the register if they want to compensate external reference error. This register does not take effect when EXT\_REF = 0 and internal reference is selected.

#### Table 12. GN\_Trim1 Register

Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8
N/A	N/A	N/A	N/A	N/A	GN10	GN9	GN8
0	0	0	0	0	0	1	1
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
GN7	GN6	GN5	GN4	GN3	GN2	GN1	GN0
1	1	1	1	1	0	1	0

ADC GN\_Trim1 register is an unsigned value. Default value used for final trimming is 1.3333 to compensate default ADC gain of 3/4. The value of GN[10:0] adds a constant to get the final gain trimming value.

 $GN_{Trim1} + CONST = GN_{Trim}$ . The binary value of CONST is 10100110101000, corresponding to a gain factor of 1.30225. After adding the default value of  $GN_{Trim1}$  register (0111111010), the final default gain trimming value is 1.3333. The MAX final gain trimming value is 1.3547 when trimming register is all '1'; MIN value is 1.30225 when register is all '0'. This gives GN trimming a ±3% range and 32ppmFS step.

# **REVISION HISTORY**

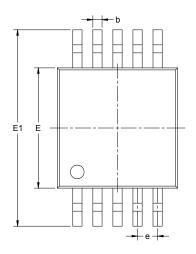
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

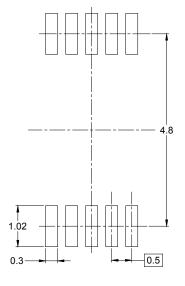
MARCH 2020 – REV.A to REV.A.1	Page
Update Figure 4 and Figure 5	
Changes from Original (DECEMBER 2019) to REV.A	Page
Changed from product preview to production data	All



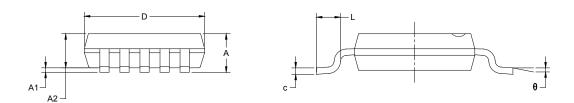
# PACKAGE OUTLINE DIMENSIONS

## MSOP-10





RECOMMENDED LAND PATTERN (Unit: mm)

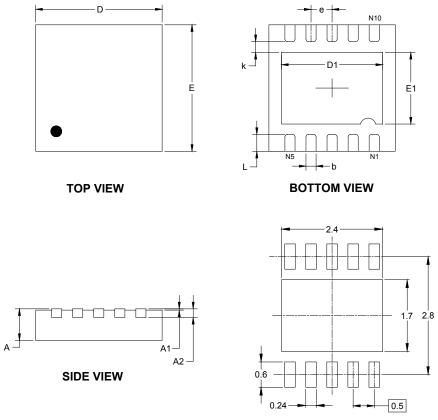


Symbol		nsions meters	Dimensions In Inches			
	MIN	MAX	MIN	MAX		
A	0.820	1.100	0.032	0.043		
A1	0.020	0.150	0.001	0.006		
A2	0.750	0.950	0.030	0.037		
b	0.180	0.280	0.007	0.011		
С	0.090	0.230	0.004	0.009		
D	2.900	3.100	0.114	0.122		
E	2.900	3.100	0.114	0.122		
E1	4.750	5.050	0.187	0.199		
е	0.500	BSC	0.020	BSC		
L	0.400	0.800	0.016	0.031		
θ	0°	6°	0°	6°		



# PACKAGE OUTLINE DIMENSIONS

# **TDFN-3×3-10L**



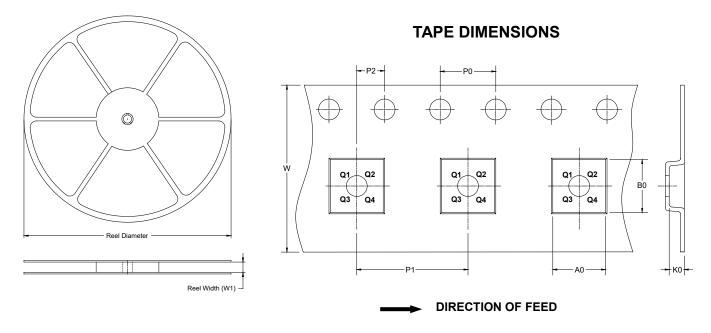
RECOMMENDED LAND PATTERN (Unit: mm)

Symbol		nsions meters	Dimensions In Inches		
5	MIN	MAX	MIN	MAX	
A	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A2	0.203	3 REF	0.008 REF		
D	2.900	3.100	0.114	0.122	
D1	2.300	2.600	0.091	0.103	
E	2.900	3.100	0.114	0.122	
E1	1.500	1.800	0.059	0.071	
k	0.200	) MIN	0.008	3 MIN	
b	0.180	0.300	0.007	0.012	
е	0.500	) TYP	0.020 TYP		
L	0.300	0.500	0.012	0.020	



# TAPE AND REEL INFORMATION

### **REEL DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

### KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
MSOP-10	13″	12.4	5.20	3.30	1.20	4.0	8.0	2.0	12.0	Q1
TDFN-3×3-10L	13″	12.4	3.35	3.35	1.13	4.0	8.0	2.0	12.0	Q1

## **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

## **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton	
13″	386	280	370	5	DD0002

